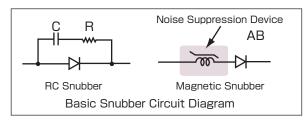
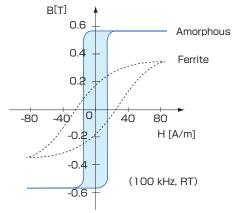
2. Noise Suppression Devices AMOBEADS



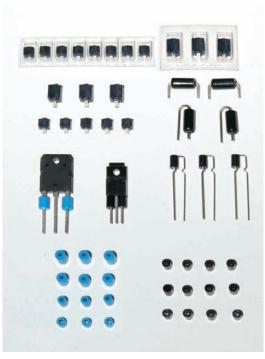
An amorphous noise suppression device is unique and completely different from conventional noise filters. Conventional noise prevention products focus on somehow minimizing the noise after it's been created, by typically trying to absorb the noise, and so their effectiveness in noise reduction is directly influenced by frequency of the circuit. Amorphous noise suppressing devices, on the other hand, focus on the source of the noise and work to prevent or minimize the noise before it has a chance to develop. The source of the electronic circuit noise is the rapid change of current or voltage, and the effectiveness of the amorphous cores in eliminating this noise is independent of frequency.

An amorphous noise suppression device is a product that takes full advantage of the unique magnetic characteristics of the cobalt based amorphous alloy. Toshiba Materials offers two noise suppression devices, "AMOBEADS®" and "SPIKE KILLERS®". AMOBEADS®" deliver excellent noise suppression results and are convenient to use by simply being slipped over the leads of the semiconductor device. "AMOBEADS®" are also available with a lead thru and in a surface mount configuration. "SPIKE KILLERS®", which are larger in size than "AMOBEADS®", most often are wire wound and are effective in eliminating or minimizing higher noise levels.



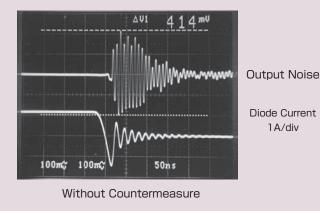


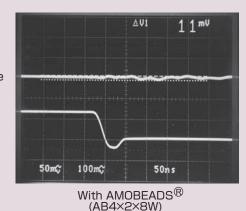
B-H Curve (typical)



Example for Noise Suppressing Effect (Chopper Converter)

With an excellent saturable characteristic, "AMOBEADS ® suppress the reverse recovery current of the diode and decrease the noise that is occurring. When the current for diode reverses and tries to go into the recovery condition, the "AMOBEADS®" displays a large inductance and oppose the generation of the recovery current. In this instance, a soft recovery is possible for core material with a smaller coercive force.





1A/div

Standard Specifications

AMOBEADS®

W series

Type No.	Finished Dimensions [mm]			Core Size [mm]*1			Total Flux*2	AL value*3	Insulating	Packing
	O.D. max	I. D. min	H.T. max	O.D.	I. D.	H.T.	φc[μWb] min	L[µH] min	Cover	Unit
AB3X2X3W	4.0	1.5	4.5	3.0	2.0	3.0	0.9	3.0		
AB3X2X4.5W	4.0	1.5	6.0	3.0	2.0	4.5	1.3	5.0		2.000
AB3X2X6W	4.0	1.5	7.5	3.0	2.0	6.0	1.8	7.0	PBT case Blue	[pcs/box]
AB4X2X4.5W	5.0	1.5	6.0	4.0	2.0	4.5	2.7	9.0		
AB4X2X6W	5.0	1.5	7.5	4.0	2.0	6.0	3.6	12.0		
AB4X2X8W	5.0	1.5	9.5	4.0	2.0	8.0	4.8	16.0		

DY series (low price) (Recommend for big demand, 10,000pcs/lot)

Type No.	Finished Dime	nsions [mm]	Total Flux*7	Insulating	Packing Unit [pcs/bag]	
1 900 140.	O.D.	H.T.	φc[μWb]	Cover		
AB2.8X4.5DY	4.0±0.2	5.7±0.3	0.9min	PBT Black	10,000	
AB3X2X3DY	4.0±0.2	4.2±0.3	0.9min	PBT Black	10,000	
AB3X2X4.5DY	4.0±0.2	5.7±0.3	1.3min	PBT Gray	10,000	
AB4X2X4.5DY	5.0±0.2	5.7±0.3	2.7min	PBT Black	5,000	
AB4X2X6DY	5.0±0.2	7.2±0.3	3.6min	PBT Black	5,000	

%Inner diameter can pass through a 1.2X0.7mm lead.

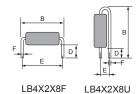


W series DY sereis

AMOBEADS®with lead

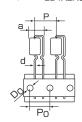
Bulk type

Type No	Fi	nished Dir	mensions (r	mm]	*4 Current	Total flux	AL Value	Insulating	Packing
Type No.	В	D	E	F	[A]	φc[μWb]	$L[\mu H]$	Cover	Unit
LB4X2X8F	16.0max	4.2±0.5	14.0±1.0	φ1.25±0.1	(8.0)	4.8	16.0	PBT case	1,000
LB4X2X8U	20.0max	4.0±0.5	5.0±1.0	φ1.25±0.1	(0.0)	min	min	Black	[pcs/box]



Radial taping

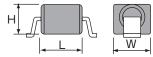
Type No.	P [mm]	Po [mm]	Do [mm]	a [mm]	d [mm]	Current*4 I [A]	Total Flux* ⁷ φc[μWb]	Packing Unit
LB2.8X4.5U	12.7	12.7	φ4.0	9.0max	φ0.8	(5)	0.9min	3,000 [pcs/box]



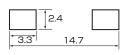
SMD Type AMOBEADS®

Type No.	Finished	d Dimensions [mm]		Lead width x thickness	lo *4 [A]	Total Flux \$\phi_c[\mu \Wb]\$	AL value L[µH]	Insulating Cover	Packing Unit [pcs/reel]
AB3X2X3SM	5.0±0.3		4.0±0.3	(1.8×0.35)	(6.0)	0.9 min	3.0	LCP case	2,000
AB4X2X6SM	6.0±0.3	8.0±0.3	5.0±0.3	(1.8×0.52)	(9.0)	3.6 min	12.0	Black	1,000

Recommended Land Pattern (mm)





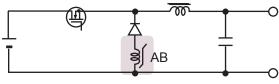


AB4X2X6SM

- *1 Reference Value *2 Minimum Guarantee on Measuring Condition: 50kHz, 80A/m(sine wave), R.T.
- *3 Measuring Condition:50kHz, 1V, 1turn, R.T.
- *4 Typical Value, using a cross section of lead
- *5 Measuring Condition:100kHz, 80A/m(sine wave), R.T. *6 Tolerance ±0.2[mm]
- *7 Converted from Inductance Value L₁ at 1kHz, 100mA(sine wave), R.T. $\phi c(\mu Wb) = 0.282 \text{ x L}_1(\mu H)$
 - ☆"AMOBEADS® " sample kits are available. Please ask sales department.
- $^{\circ}$ "AMOBEADS $^{\circ}$ " and "SPIKE KILLER $^{\circ}$ ": Registered trademarks of TOSHIBA MATERIALS Co., Ltd. $^{\circ}$ "AMOBEADS $^{\circ}$ " and "SPIKE KILLER $^{\circ}$ ": Resistered in U.S.A., France, Germany, U.K., Japan.

Examples of Applied Circuits and their Characteristics

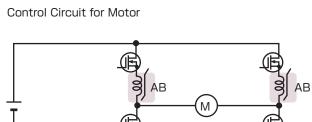
Application of Amorphous Noise Suppression Devices



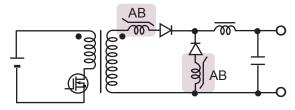
Chopper Converter



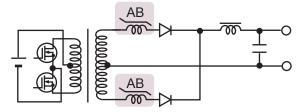
Flyback Converter



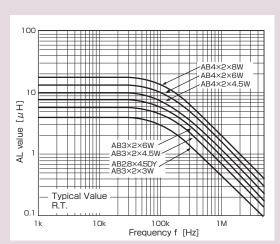
Motor Driving Circuit



Forward Converter

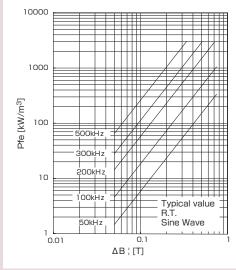


Push-pull Converter



Frequency Characteristics of Inductance

Characteristics (Typical value)



Coreloss Characteristic [AMOBEADS®]

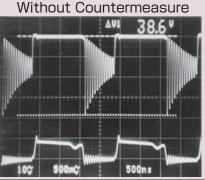
 $Flux(\phi)$ Decline Ratio vs. Temperature

Effects of Noise Suppression by AMOBEADS®

Spike Voltage Suppression

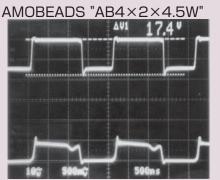
Spike voltage can be reduced and ringing phenomena can also be prevented by AMOBEADS. Also Schottky barrier diode (SBD) can be protected from over voltage.

Frequency: 500kHz Output Voltage - Current :5V-20A



Diode Voltage VD 10V/div

Diode Current ID 5A/div



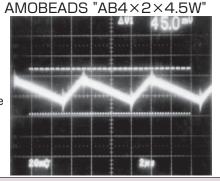
Output Noise Reduction

When the ferrite is replaced by AMOBEADS at the secondary output diode (FRD) of the forward converter circuit, the output noise can be tremendously reduced, not only the noise peak level but also the amplitude range.

Frequency: 150kHz Output Voltage - Current

RC Snubber +Ferrite Beads

Output Noise VΝ 20mv/div



AMOBEADS "AB4×2×4.5W"

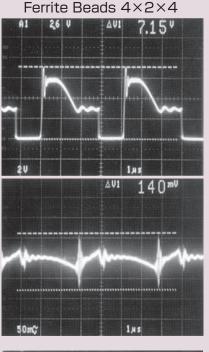
: 15V-10A

Primary Surge Voltage

When the ferrite is replaced by AMOBEADS at the secondary output diode (SBD) of the forward converter circuit, the output noise and harmful influence to the primary stage can be reduced These effects are based on the inclination of the actual BH curves between amorphous and ferrite materials.

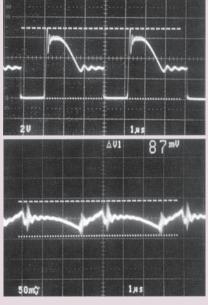
Frequency: 250kHz Output Voltage - Current :5V-15A

Output Noise

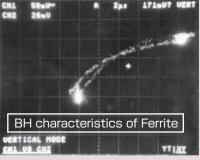


MOS-FET Drain-Source Voltage VDS 200V/div

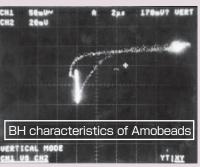




Actual BH Curve



В



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Toshiba:

<u>AB4X2X4.5W</u> <u>AB4X2X8W</u> <u>AB4X2X6SM</u> <u>LB 2.8X4.5U</u> <u>AB3X2X6W</u> <u>AB 3X2X3DY</u> <u>AB3X2X4.5DY</u> <u>AB 2.8X4.5DY</u> AB3X2X3W AB3X2X4.5W LB4X2X8U LB2.8X4.5U AB2.8X4.5DY AB3X2X3DY